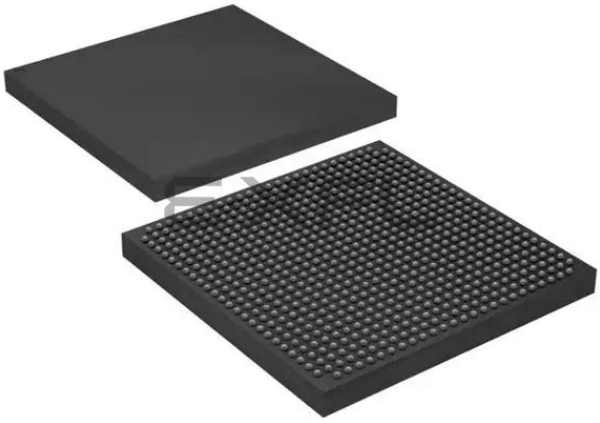

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Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

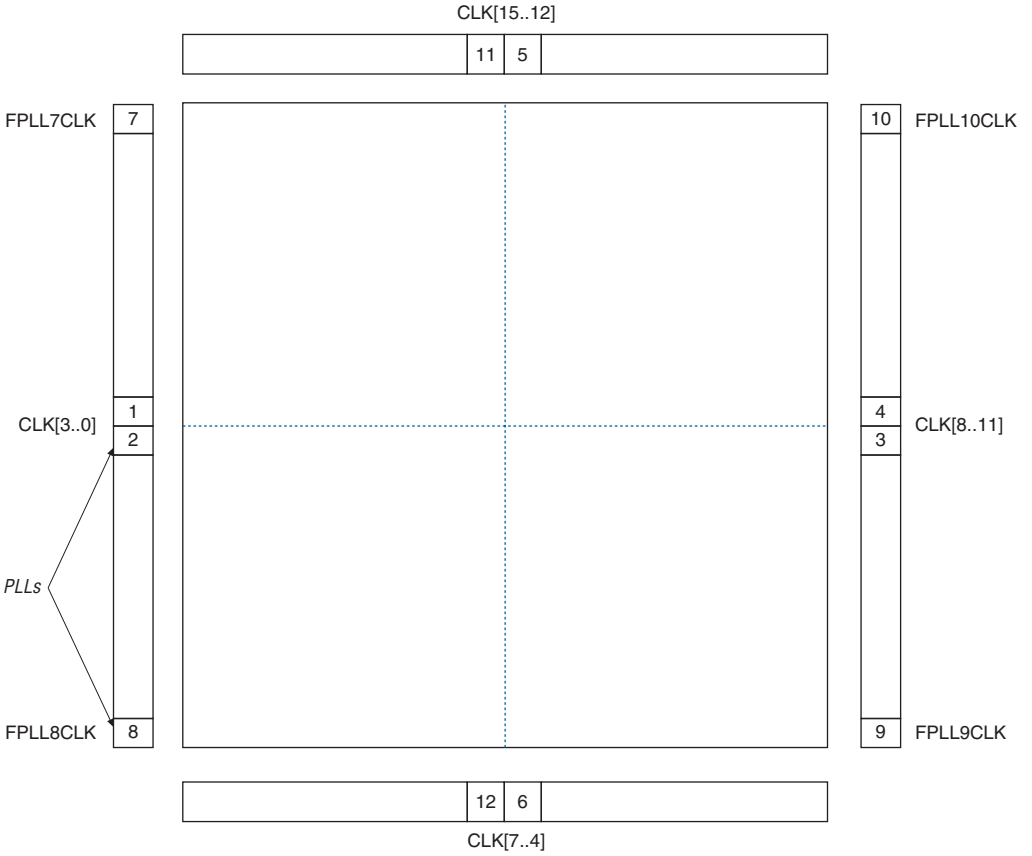
Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Obsolete
Number of LABs/CLBs	780
Number of Logic Elements/Cells	15600
Total RAM Bits	419328
Number of I/O	366
Number of Gates	-
Voltage - Supply	1.15V ~ 1.25V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	672-BBGA
Supplier Device Package	672-FBGA (27x27)
Purchase URL	https://www.e-xfl.com/product-detail/intel/ep2s15f672c4n

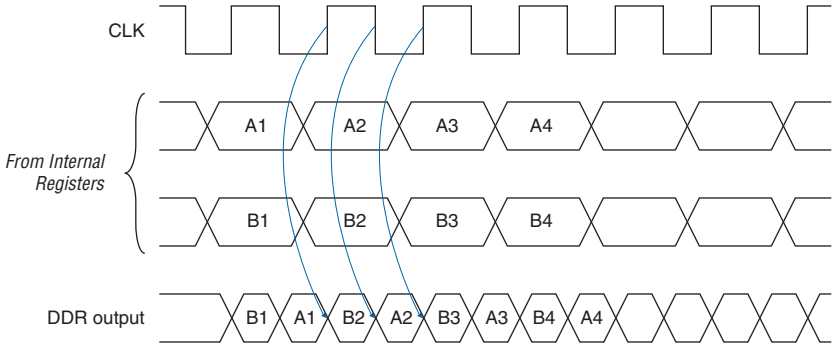
Figure 2–40 shows a top-level diagram of the Stratix II device and PLL floorplan.

Figure 2–40. PLL Locations



Figures 2–41 and 2–42 shows the global and regional clocking from the fast PLL outputs and the side clock pins.

Figure 2–55. Output TIming Diagram in DDR Mode



The Stratix II IOE operates in bidirectional DDR mode by combining the DDR input and DDR output configurations. The negative-edge-clocked OE register holds the OE signal inactive until the falling edge of the clock. This is done to meet DDR SDRAM timing requirements.

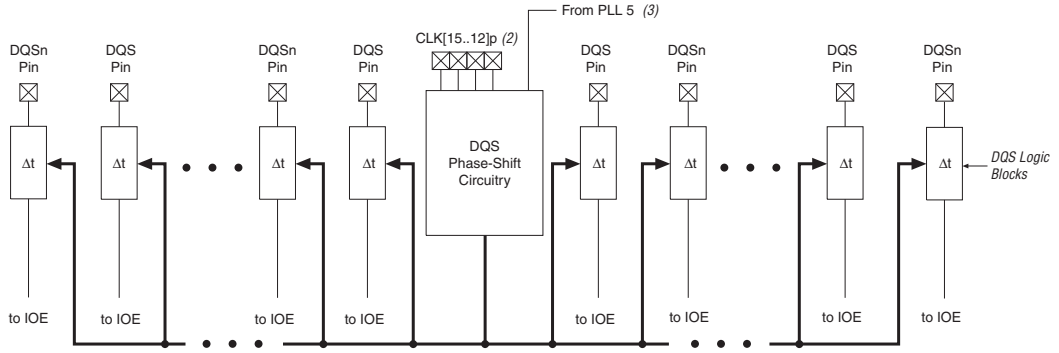
External RAM Interfacing

In addition to the six I/O registers in each IOE, Stratix II devices also have dedicated phase-shift circuitry for interfacing with external memory interfaces. Stratix II devices support DDR and DDR2 SDRAM, QDR II SRAM, RLDRAM II, and SDR SDRAM memory interfaces. In every Stratix II device, the I/O banks at the top (banks 3 and 4) and bottom (banks 7 and 8) of the device support DQ and DQS signals with DQ bus modes of ×4, ×8/×9, ×16/×18, or ×32/×36. Table 2–14 shows the number of DQ and DQS buses that are supported per device.

Table 2–14. DQS & DQ Bus Mode Support (Part 1 of 2) *Note (1)*

Device	Package	Number of ×4 Groups	Number of ×8/×9 Groups	Number of ×16/×18 Groups	Number of ×32/×36 Groups
EP2S15	484-pin FineLine BGA	8	4	0	0
	672-pin FineLine BGA	18	8	4	0
EP2S30	484-pin FineLine BGA	8	4	0	0
	672-pin FineLine BGA	18	8	4	0
EP2S60	484-pin FineLine BGA	8	4	0	0
	672-pin FineLine BGA	18	8	4	0
	1,020-pin FineLine BGA	36	18	8	4

Figure 2–56. DQS Phase-Shift Circuitry *Notes (1), (2), (3), (4)*



Notes to Figure 2–56:

(1) There are up to 18 pairs of DQS and DQSn pins available on the top or the bottom of the Stratix II device. There are up to 10 pairs on the right side and 8 pairs on the left side of the DQS phase-shift circuitry.

(2) The Δt module represents the DQS logic block.

(3) Clock pins `CLK[15..12]p` feed the phase-shift circuitry on the top of the device and clock pins `CLK[7..4]p` feed the phase circuitry on the bottom of the device. You can also use a PLL clock output as a reference clock to the phase-shift circuitry.

(4) You can only use PLL 5 to feed the DQS phase-shift circuitry on the top of the device and PLL 6 to feed the DQS phase-shift circuitry on the bottom of the device.

These dedicated circuits combined with enhanced PLL clocking and phase-shift ability provide a complete hardware solution for interfacing to high-speed memory.

For more information on external memory interfaces, refer to the *External Memory Interfaces in Stratix II & Stratix II GX Devices* chapter in volume 2 of the *Stratix II Device Handbook* or the *Stratix II GX Device Handbook*.

Programmable Drive Strength

The output buffer for each Stratix II device I/O pin has a programmable drive strength control for certain I/O standards. The LVTTL, LVCMOS, SSTL, and HSTL standards have several levels of drive strength that the user can control. The default setting used in the Quartus II software is the maximum current strength setting that is used to achieve maximum I/O performance. For all I/O standards, the minimum setting is the lowest drive strength that guarantees the I_{OH}/I_{OL} of the standard. Using minimum settings provides signal slew rate control to reduce system noise and signal overshoot.

Table 2–23. EP2S60 Differential Channels *Note (1)*

Package	Transmitter/ Receiver	Total Channels	Center Fast PLLs				Corner Fast PLLs *(4)*			
			PLL 1	PLL 2	PLL 3	PLL 4	PLL 7	PLL 8	PLL 9	PLL 10
484-pin FineLine BGA	Transmitter	38 *(2)*	10	9	9	10	10	9	9	10
		(3)	19	19	19	19	-	-	-	-
	Receiver	42 *(2)*	11	10	10	11	11	10	10	11
		(3)	21	21	21	21	-	-	-	-
672-pin FineLine BGA	Transmitter	58 *(2)*	16	13	13	16	16	13	13	16
		(3)	29	29	29	29	-	-	-	-
	Receiver	62 *(2)*	17	14	14	17	17	14	14	17
		(3)	31	31	31	31	-	-	-	-
1,020-pin FineLine BGA	Transmitter	84 *(2)*	21	21	21	21	21	21	21	21
		(3)	42	42	42	42	-	-	-	-
	Receiver	84 *(2)*	21	21	21	21	21	21	21	21
		(3)	42	42	42	42	-	-	-	-

Table 2–24. EP2S90 Differential Channels *Note (1)*

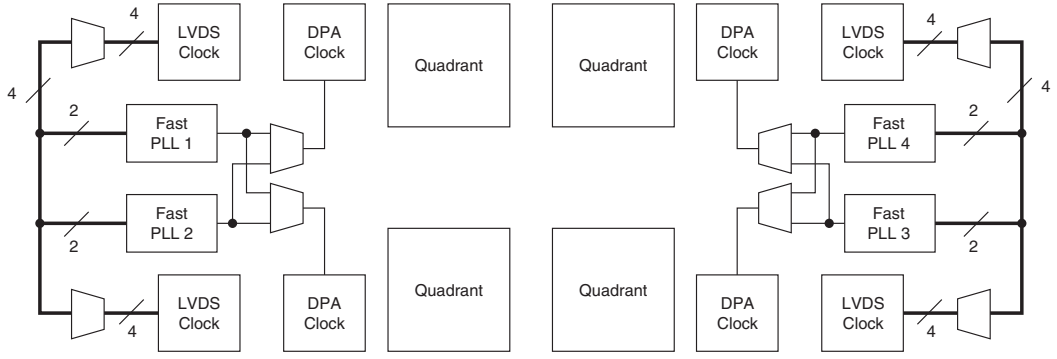
Package	Transmitter/ Receiver	Total Channels	Center Fast PLLs				Corner Fast PLLs *(4)*			
			PLL 1	PLL 2	PLL 3	PLL 4	PLL 7	PLL 8	PLL 9	PLL 10
484-pin Hybrid FineLine BGA	Transmitter	38 *(2)*	10	9	9	10	-	-	-	-
		(3)	19	19	19	19	-	-	-	-
	Receiver	42 *(2)*	11	10	10	11	-	-	-	-
		(3)	21	21	21	21	-	-	-	-
780-pin FineLine BGA	Transmitter	64 *(2)*	16	16	16	16	-	-	-	
		(3)	32	32	32	32	-	-	-	-
	Receiver	68 *(2)*	17	17	17	17	-	-	-	-
		(3)	34	34	34	34	-	-	-	
1,020-pin FineLine BGA	Transmitter	90 *(2)*	23	22	22	23	23	22	22	23
		(3)	45	45	45	45	-	-	-	-
	Receiver	94 *(2)*	23	24	24	23	23	24	24	23
		(3)	46	46	46	46	-	-	-	-
1,508-pin FineLine BGA	Transmitter	118 *(2)*	30	29	29	30	30	29	29	30
		(3)	59	59	59	59	-	-	-	-
	Receiver	118 *(2)*	30	29	29	30	30	29	29	30
		(3)	59	59	59	59	-	-	-	-

For high-speed source synchronous interfaces such as POS-PHY 4, Parallel RapidIO, and HyperTransport, the source synchronous clock rate is not a byte- or SERDES-rate multiple of the data rate. Byte alignment is necessary for these protocols since the source synchronous clock does not provide a byte or word boundary since the clock is one half the data rate, not one eighth. The Stratix II device's high-speed differential I/O circuitry provides dedicated data realignment circuitry for user-controlled byte boundary shifting. This simplifies designs while saving ALM resources. You can use an ALM-based state machine to signal the shift of receiver byte boundaries until a specified pattern is detected to indicate byte alignment.

Fast PLL & Channel Layout

The receiver and transmitter channels are interleaved such that each I/O bank on the left and right side of the device has one receiver channel and one transmitter channel per LAB row. Figure 2–60 shows the fast PLL and channel layout in the EP2S15 and EP2S30 devices. Figure 2–61 shows the fast PLL and channel layout in the EP2S60 to EP2S180 devices.

Figure 2–60. Fast PLL & Channel Layout in the EP2S15 & EP2S30 Devices *Note (1)*



Note to Figure 2–60:
(1) See Table 2–21 for the number of channels each device supports.

Table 2–27. Document Revision History (Part 2 of 2)

Date and Document Version	Changes Made	Summary of Changes
January 2005, v2.0	• Updated the "MultiVolt I/O Interface" and "TriMatrix Memory" sections. • Updated Tables 2–3, 2–17, and 2–19.	—
October 2004, v1.2	• Updated Tables 2–9, 2–16, 2–26, and 2–27.	—
July 2004, v1.1	• Updated note to Tables 2–9 and 2–16. • Updated Tables 2–16, 2–17, 2–18, 2–19, and 2–20. • Updated Figures 2–41, 2–42, and 2–57. • Removed 3 from list of SERDES factor *J*. • Updated "High-Speed Differential I/O with DPA Support" section. • In "Dedicated Circuitry with DPA Support" section, removed XSBI and changed RapidIO to Parallel RapidIO.	—
February 2004, v1.0	Added document to the Stratix II Device Handbook.	—

Table 3–1. Stratix II JTAG Instructions

JTAG Instruction	Instruction Code	Description
SAMPLE/PRELOAD	00 0000 0101	Allows a snapshot of signals at the device pins to be captured and examined during normal device operation, and permits an initial data pattern to be output at the device pins. Also used by the SignalTap II embedded logic analyzer.
EXTEST *(1)*	00 0000 1111	Allows the external circuitry and board-level interconnects to be tested by forcing a test pattern at the output pins and capturing test results at the input pins.
BYPASS	11 1111 1111	Places the 1-bit bypass register between the TDI and TDO pins, which allows the BST data to pass synchronously through selected devices to adjacent devices during normal device operation.
USERCODE	00 0000 0111	Selects the 32-bit USERCODE register and places it between the TDI and TDO pins, allowing the USERCODE to be serially shifted out of TDO.
IDCODE	00 0000 0110	Selects the IDCODE register and places it between TDI and TDO, allowing the IDCODE to be serially shifted out of TDO.
HIGHZ *(1)*	00 0000 1011	Places the 1-bit bypass register between the TDI and TDO pins, which allows the BST data to pass synchronously through selected devices to adjacent devices during normal device operation, while tri-stating all of the I/O pins.
CLAMP *(1)*	00 0000 1010	Places the 1-bit bypass register between the TDI and TDO pins, which allows the BST data to pass synchronously through selected devices to adjacent devices during normal device operation while holding I/O pins to a state defined by the data in the boundary-scan register.
ICR instructions		Used when configuring a Stratix II device via the JTAG port with a USB Blaster, MasterBlaster™, ByteBlasterMV™, or ByteBlaster II download cable, or when using a **.jam** or **.jbc** via an embedded processor or JRunner.
PULSE_NCONFIG	00 0000 0001	Emulates pulsing the nCONFIG pin low to trigger reconfiguration even though the physical pin is unaffected.
CONFIG_IO *(2)*	00 0000 1101	Allows configuration of I/O standards through the JTAG chain for JTAG testing. Can be executed before, during, or after configuration. Stops configuration if executed during configuration. Once issued, the CONFIG_IO instruction holds nSTATUS low to reset the configuration device. nSTATUS is held low until the IOE configuration register is loaded and the TAP controller state machine transitions to the UPDATE_DR state.
SignalTap II instructions		Monitors internal device operation with the SignalTap II embedded logic analyzer.

Notes to Table 3–1:

(1) Bus hold and weak pull-up resistor features override the high-impedance state of HIGHZ, CLAMP, and EXTEST.

(2) For more information on using the CONFIG_IO instruction, see the *MorphIO: An I/O Reconfiguration Solution for Altera Devices White Paper.*

the Device & Pin Options dialog box in the Quartus II software uses a 32-bit CRC circuit to ensure data reliability and is one of the best options for mitigating SEU.

You can implement the error detection CRC feature with existing circuitry in Stratix II devices, eliminating the need for external logic. For Stratix II devices, CRC is computed by the device during configuration and checked against an automatically computed CRC during normal operation. The CRC_ERROR pin reports a soft error when configuration SRAM data is corrupted, triggering device reconfiguration.

Custom-Built Circuitry

Dedicated circuitry is built in the Stratix II devices to perform error detection automatically. This error detection circuitry in Stratix II devices constantly checks for errors in the configuration SRAM cells while the device is in user mode. You can monitor one external pin for the error and use it to trigger a re-configuration cycle. You can select the desired time between checks by adjusting a built-in clock divider.

Software Interface

In the Quartus II software version 4.1 and later, you can turn on the automated error detection CRC feature in the Device & Pin Options dialog box. This dialog box allows you to enable the feature and set the internal frequency of the CRC between 400 kHz to 50 MHz. This controls the rate that the CRC circuitry verifies the internal configuration SRAM bits in the FPGA device.

For more information on CRC, refer to *AN 357: Error Detection Using CRC in Altera FPGA Devices*.

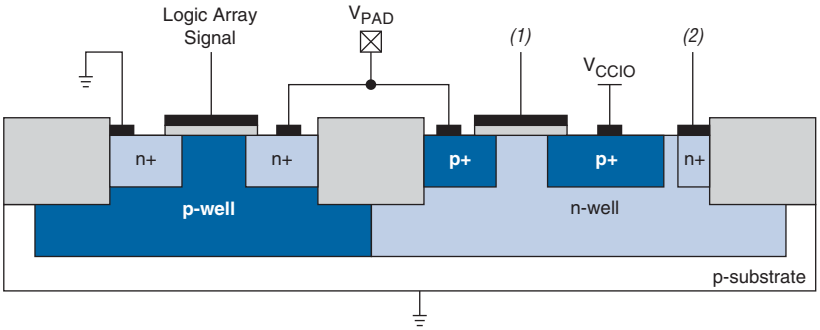
Document Revision History

Table 3–7 shows the revision history for this chapter.

Table 3–7. Document Revision History (Part 1 of 2)

Date and Document Version	Changes Made	Summary of Changes
May 2007, v4.2	Moved Document Revision History section to the end of the chapter.	—
	Updated the "Temperature Sensing Diode (TSD)" section.	—

Figure 4–2. Transistor Level Diagram of FPGA Device I/O Buffers



Notes to Figure 4–2:
(1) This is the logic array signal or the larger of either the V_{CCIO} or V_{PAD} signal.
(2) This is the larger of either the V_{CCIO} or V_{PAD} signal.

Power-On Reset Circuitry

Stratix II devices have a POR circuit to keep the whole device system in reset state until the power supply voltage levels have stabilized during power-up. The POR circuit monitors the V_{CCINT}, V_{CCIO}, and V_{CCPD} voltage levels and tri-states all the user I/O pins while V_{CC} is ramping up until normal user levels are reached. The POR circuitry also ensures that all eight I/O bank V_{CCIO} voltages, V_{CCPD} voltage, as well as the logic array V_{CCINT} voltage, reach an acceptable level before configuration is triggered. After the Stratix II device enters user mode, the POR circuit continues to monitor the V_{CCINT} voltage level so that a brown-out condition during user mode can be detected. If there is a V_{CCINT} voltage sag below the Stratix II operational level during user mode, the POR circuit resets the device.

When power is applied to a Stratix II device, a power-on-reset event occurs if V_{CC} reaches the recommended operating range within a certain period of time (specified as a maximum V_{CC} rise time). The maximum V_{CC} rise time for Stratix II device is 100 ms. Stratix II devices provide a dedicated input pin (PORSEL) to select POR delay times of 12 or 100 ms during power-up. When the PORSEL pin is connected to ground, the POR time is 100 ms. When the PORSEL pin is connected to V_{CC}, the POR time is 12 ms.

5. DC & Switching Characteristics

SII51005-4.5

Operating Conditions

Stratix® II devices are offered in both commercial and industrial grades. Industrial devices are offered in -4 speed grades and commercial devices are offered in -3 (fastest), -4, -5 speed grades.

Tables 5–1 through 5–32 provide information about absolute maximum ratings, recommended operating conditions, DC electrical characteristics, and other specifications for Stratix II devices.

Absolute Maximum Ratings

Table 5–1 contains the absolute maximum ratings for the Stratix II device family.

Table 5–1. Stratix II Device Absolute Maximum Ratings *Notes (1), (2), (3)*

Symbol	Parameter	Conditions	Minimum	Maximum	Unit
V_{CCINT}	Supply voltage	With respect to ground	–0.5	1.8	V
V_{CCIO}	Supply voltage	With respect to ground	–0.5	4.6	V
V_{CCPD}	Supply voltage	With respect to ground	–0.5	4.6	V
V_{CCA}	Analog power supply for PLLs	With respect to ground	–0.5	1.8	V
V_{CCD}	Digital power supply for PLLs	With respect to ground	–0.5	1.8	V
V_I	DC input voltage *(4)*		–0.5	4.6	V
I_{OUT}	DC output current, per pin		–25	40	mA
T_{STG}	Storage temperature	No bias	–65	150	°C
T_J	Junction temperature	BGA packages under bias	–55	125	°C

Notes to Tables 5–1

(1) See the *Operating Requirements for Altera Devices Data Sheet*.
(2) Conditions beyond those listed in Table 5–1 may cause permanent damage to a device. Additionally, device operation at the absolute maximum ratings for extended periods of time may have adverse affects on the device.
(3) Supply voltage specifications apply to voltage readings taken at the device pins, not at the power supply.
(4) During transitions, the inputs may overshoot to the voltage shown in Table 5–2 based upon the input duty cycle. The DC case is equivalent to 100% duty cycle. During transitions, the inputs may undershoot to –2.0 V for input currents less than 100 mA and periods shorter than 20 ns.

Figure 5–6. Measurement Setup for t_{zx}

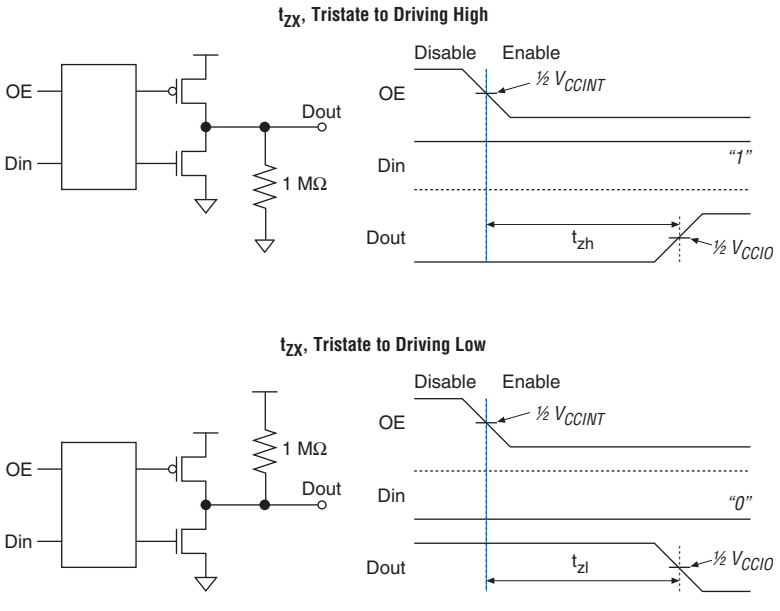


Table 5–35 specifies the input timing measurement setup.

Table 5–35. Timing Measurement Methodology for Input Pins (Part 1 of 2) *Notes (1)–(4)*

I/O Standard	Measurement Conditions			Measurement Point
	V_{CCIO} (V)	V_{REF} (V)	Edge Rate (ns)	V_{MEAS} (V)
LVTTL *(5)*	3.135		3.135	1.5675
LVCMOS *(5)*	3.135		3.135	1.5675
2.5 V *(5)*	2.375		2.375	1.1875
1.8 V *(5)*	1.710		1.710	0.855
1.5 V *(5)*	1.425		1.425	0.7125
PCI *(6)*	2.970		2.970	1.485
PCI-X *(6)*	2.970		2.970	1.485
SSTL-2 Class I	2.325	1.163	2.325	1.1625
SSTL-2 Class II	2.325	1.163	2.325	1.1625
SSTL-18 Class I	1.660	0.830	1.660	0.83
SSTL-18 Class II	1.660	0.830	1.660	0.83
1.8-V HSTL Class I	1.660	0.830	1.660	0.83

Table 5–36. Stratix II Performance Notes (Part 3 of 6) *Note (1)*

Applications		Resources Used			Performance				
		ALUTs	TriMatrix Memory Blocks	DSP Blocks	-3 Speed Grade *(2)*	-3 Speed Grade *(3)*	-4 Speed Grade	-5 Speed Grade	Unit
DSP block	9 × 9-bit multiplier *(5)*	0	0	1	430.29	409.16	373.13	320.10	MHz
	18 × 18-bit multiplier *(5)*	0	0	1	410.17	390.01	356.12	305.06	MHz
	18 × 18-bit multiplier *(7)*	0	0	1	450.04	428.08	391.23	335.12	MHz
	36 × 36-bit multiplier *(5)*	0	0	1	250.00	238.15	217.48	186.60	MHz
	36 × 36-bit multiplier *(6)*	0	0	1	410.17	390.01	356.12	305.06	MHz
	18-bit, four-tap FIR filter	0	0	1	410.17	390.01	356.12	305.06	MHz
Larger designs	8-bit,16-tap parallel FIR filter	58	0	4	259.06	240.61	217.15	185.01	MHz
	8-bit, 1024-point, streaming, three multipliers and five adders FFT function	2976	22	9	398.72	364.03	355.23	306.37	MHz
	8-bit, 1024-point, streaming, four multipliers and two adders FFT function	2781	22	12	398.56	409.16	347.22	311.13	MHz
	8-bit, 1024-point, single output, one parallel FFT engine, burst, three multipliers and five adders FFT function	984	5	3	425.17	365.76	346.98	292.39	MHz
	8-bit, 1024-point, single output, one parallel FFT engine, burst, four multipliers and two adders FFT function	919	5	4	427.53	378.78	357.14	307.59	MHz

Table 5–40. M512 Block Internal Timing Microparameters (Part 2 of 2) *Note (1)*

Symbol	Parameter	-3 Speed Grade (2)		-3 Speed Grade (3)		-4 Speed Grade		-5 Speed Grade		Unit
		Min (4)	Max	Min (4)	Max	Min (5)	Max	Min (4)	Max	
$t_{M512DATACO1}$	Clock-to-output delay when using output registers	298	478	298	501	284 298	548	298	640	ps
$t_{M512DATACO2}$	Clock-to-output delay without output registers	2,102	2,345	2,102	2,461	2,003 2,102	2,695	2,102	3,141	ps
$t_{M512CLKL}$	Minimum clock low time	1,315		1,380		1,512 1,512		1,762		ps
$t_{M512CLKH}$	Minimum clock high time	1,315		1,380		1,512 1,512		1,762		ps
$t_{M512CLR}$	Minimum clear pulse width	144		151		165 165		192		ps

Notes to Table 5–40:

(1) F_{MAX} of M512 block obtained using the Quartus II software does not necessarily equal to 1/TM512RC.
(2) These numbers apply to -3 speed grade EP2S15, EP2S30, EP2S60, and EP2S90 devices.
(3) These numbers apply to -3 speed grade EP2S130 and EP2S180 devices.
(4) For the -3 and -5 speed grades, the minimum timing is for the commercial temperature grade. Only -4 speed grade devices offer the industrial temperature grade.
(5) For the -4 speed grade, the first number is the minimum timing parameter for industrial devices. The second number is the minimum timing parameter for commercial devices.

Table 5–41. M4K Block Internal Timing Microparameters (Part 1 of 2) *Note (1)*

Symbol	Parameter	-3 Speed Grade (2)		-3 Speed Grade (3)		-4 Speed Grade		-5 Speed Grade		Unit
		Min (4)	Max	Min (4)	Max	Min (5)	Max	Min (4)	Max	
t_{M4KRC}	Synchronous read cycle time	1,462	2,240	1,462	2,351	1,393 1,462	2,575	1,462	3,000	ps
$t_{M4KWERESU}$	Write or read enable setup time before clock	22		23		25 25		29		ps
$t_{M4KWEREH}$	Write or read enable hold time after clock	203		213		233 233		272		ps
$t_{M4KBESU}$	Byte enable setup time before clock	22		23		25 25		29		ps
t_{M4KBEH}	Byte enable hold time after clock	203		213		233 233		272		ps

Table 5–73. Stratix II I/O Input Delay for Column Pins (Part 3 of 3)

I/O Standard	Parameter	Minimum Timing		-3 Speed Grade (2)	-3 Speed Grade (3)	-4 Speed Grade	-5 Speed Grade	Unit
		Industrial	Commercial					
1.2-V HSTL	t_{PI}	645	677	1194	1252	-	-	ps
	t_{PCOUT}	379	398	758	795	-	-	ps

Notes for Table 5–73:
(1) These I/O standards are only supported on DQS pins.
(2) These numbers apply to -3 speed grade EP2S15, EP2S30, EP2S60, and EP2S90 devices.
(3) These numbers apply to -3 speed grade EP2S130 and EP2S180 devices.

Table 5–74. Stratix II I/O Input Delay for Row Pins (Part 1 of 2)

I/O Standard	Parameter	Minimum Timing		-3 Speed Grade (1)	-3 Speed Grade (2)	-4 Speed Grade	-5 Speed Grade	Unit
		Industrial	Commercial					
LVTTL	t_{PI}	715	749	1287	1350	1477	1723	ps
	t_{PCOUT}	391	410	760	798	873	1018	ps
2.5 V	t_{PI}	726	761	1273	1335	1461	1704	ps
	t_{PCOUT}	402	422	746	783	857	999	ps
1.8 V	t_{PI}	788	827	1427	1497	1639	1911	ps
	t_{PCOUT}	464	488	900	945	1035	1206	ps
1.5 V	t_{PI}	792	830	1498	1571	1720	2006	ps
	t_{PCOUT}	468	491	971	1019	1116	1301	ps
LVCMOS	t_{PI}	715	749	1287	1350	1477	1723	ps
	t_{PCOUT}	391	410	760	798	873	1018	ps
SSTL-2 Class I	t_{PI}	547	573	879	921	1008	1176	ps
	t_{PCOUT}	223	234	352	369	404	471	ps
SSTL-2 Class II	t_{PI}	547	573	879	921	1008	1176	ps
	t_{PCOUT}	223	234	352	369	404	471	ps
SSTL-18 Class I	t_{PI}	577	605	960	1006	1101	1285	ps
	t_{PCOUT}	253	266	433	454	497	580	ps
SSTL-18 Class II	t_{PI}	577	605	960	1006	1101	1285	ps
	t_{PCOUT}	253	266	433	454	497	580	ps
1.5-V HSTL Class I	t_{PI}	602	631	1056	1107	1212	1413	ps
	t_{PCOUT}	278	292	529	555	608	708	ps

Table 5–74. Stratix II I/O Input Delay for Row Pins (Part 2 of 2)

I/O Standard	Parameter	Minimum Timing		-3 Speed Grade (1)	-3 Speed Grade (2)	-4 Speed Grade	-5 Speed Grade	Unit
		Industrial	Commercial					
1.5-V HSTL Class II	t_{PI}	602	631	1056	1107	1212	1413	ps
	t_{PCOUT}	278	292	529	555	608	708	ps
1.8-V HSTL Class I	t_{PI}	577	605	960	1006	1101	1285	ps
	t_{PCOUT}	253	266	433	454	497	580	ps
1.8-V HSTL Class II	t_{PI}	577	605	960	1006	1101	1285	ps
	t_{PCOUT}	253	266	433	454	497	580	ps
LVDS	t_{PI}	515	540	948	994	1088	1269	ps
	t_{PCOUT}	191	201	421	442	484	564	ps
HyperTransport	t_{PI}	515	540	948	994	1088	1269	ps
	t_{PCOUT}	191	201	421	442	484	564	ps

Notes for Table 5–74:
(1) These numbers apply to -3 speed grade EP2S15, EP2S30, EP2S60, and EP2S90 devices.
(2) These numbers apply to -3 speed grade EP2S130 and EP2S180 devices.

Table 5–75. Stratix II I/O Output Delay for Column Pins (Part 1 of 8)

I/O Standard	Drive Strength	Parameter	Minimum Timing		-3 Speed Grade (3)	-3 Speed Grade (4)	-4 Speed Grade	-5 Speed Grade	Unit
			Industrial	Commercial					
LVTTL	4 mA	t_{OP}	1178	1236	2351	2467	2702	2820	ps
		t_{DIP}	1198	1258	2417	2537	2778	2910	ps
	8 mA	t_{OP}	1041	1091	2036	2136	2340	2448	ps
		t_{DIP}	1061	1113	2102	2206	2416	2538	ps
	12 mA	t_{OP}	976	1024	2036	2136	2340	2448	ps
		t_{DIP}	996	1046	2102	2206	2416	2538	ps
	16 mA	t_{OP}	951	998	1893	1986	2176	2279	ps
		t_{DIP}	971	1020	1959	2056	2252	2369	ps
	20 mA	t_{OP}	931	976	1787	1875	2054	2154	ps
		t_{DIP}	951	998	1853	1945	2130	2244	ps
	24 mA (1)	t_{OP}	924	969	1788	1876	2055	2156	ps
		t_{DIP}	944	991	1854	1946	2131	2246	ps

Table 5–75. Stratix II I/O Output Delay for Column Pins (Part 3 of 8)

I/O Standard	Drive Strength	Parameter	Minimum Timing		-3 Speed Grade (3)	-3 Speed Grade (4)	-4 Speed Grade	-5 Speed Grade	Unit
			Industrial	Commercial					
1.8 V	2 mA	t_{OP}	1042	1093	2904	3048	3338	3472	ps
		t_{DIP}	1062	1115	2970	3118	3414	3562	ps
	4 mA	t_{OP}	1047	1098	2248	2359	2584	2698	ps
		t_{DIP}	1067	1120	2314	2429	2660	2788	ps
	6 mA	t_{OP}	974	1022	2024	2124	2326	2434	ps
		t_{DIP}	994	1044	2090	2194	2402	2524	ps
	8 mA	t_{OP}	976	1024	1947	2043	2238	2343	ps
		t_{DIP}	996	1046	2013	2113	2314	2433	ps
	10 mA	t_{OP}	933	978	1882	1975	2163	2266	ps
		t_{DIP}	953	1000	1948	2045	2239	2356	ps
	12 mA (1)	t_{OP}	934	979	1833	1923	2107	2209	ps
		t_{DIP}	954	1001	1899	1993	2183	2299	ps
1.5 V	2 mA	t_{OP}	1023	1073	2505	2629	2879	3002	ps
		t_{DIP}	1043	1095	2571	2699	2955	3092	ps
	4 mA	t_{OP}	963	1009	2023	2123	2325	2433	ps
		t_{DIP}	983	1031	2089	2193	2401	2523	ps
	6 mA	t_{OP}	966	1012	1923	2018	2210	2315	ps
		t_{DIP}	986	1034	1989	2088	2286	2405	ps
	8 mA (1)	t_{OP}	926	971	1878	1970	2158	2262	ps
		t_{DIP}	946	993	1944	2040	2234	2352	ps
SSTL-2 Class I	8 mA	t_{OP}	913	957	1715	1799	1971	2041	ps
		t_{DIP}	933	979	1781	1869	2047	2131	ps
	12 mA (1)	t_{OP}	896	940	1672	1754	1921	1991	ps
		t_{DIP}	916	962	1738	1824	1997	2081	ps
SSTL-2 Class II	16 mA	t_{OP}	876	918	1609	1688	1849	1918	ps
		t_{DIP}	896	940	1675	1758	1925	2008	ps
	20 mA	t_{OP}	877	919	1598	1676	1836	1905	ps
		t_{DIP}	897	941	1664	1746	1912	1995	ps
	24 mA (1)	t_{OP}	872	915	1596	1674	1834	1903	ps
		t_{DIP}	892	937	1662	1744	1910	1993	ps

Table 5–80. Maximum DCD for Non-DDIO Output on Row I/O Pins (Part 2 of 2) *Note (1)*

Row I/O Output Standard	Maximum DCD for Non-DDIO Output		
	-3 Devices	-4 & -5 Devices	Unit
1.8 V	180	180	ps
1.5-V LVCMOS	165	195	ps
SSTL-2 Class I	115	145	ps
SSTL-2 Class II	95	125	ps
SSTL-18 Class I	55	85	ps
1.8-V HSTL Class I	80	100	ps
1.5-V HSTL Class I	85	115	ps
LVDS/ HyperTransport technology	55	80	ps

Note to Table 5–80:
(1) The DCD specification is based on a no logic array noise condition.

Here is an example for calculating the DCD as a percentage for a non-DDIO output on a row I/O on a -3 device:

If the non-DDIO output I/O standard is SSTL-2 Class II, the maximum DCD is 95 ps (see Table 5–80). If the clock frequency is 267 MHz, the clock period T is:

T = 1/ f = 1 / 267 MHz = 3.745 ns = 3745 ps

To calculate the DCD as a percentage:

(T/2 – DCD) / T = (3745ps/2 – 95ps) / 3745ps = 47.5% (for low boundary)

(T/2 + DCD) / T = (3745ps/2 + 95ps) / 3745ps = 52.5% (for high boundary)

High-Speed I/O Specifications

Table 5–88 provides high-speed timing specifications definitions.

Table 5–88. High-Speed Timing Specifications & Definitions

High-Speed Timing Specifications	Definitions
t_C	High-speed receiver/transmitter input and output clock period.
f_{HSCLK}	High-speed receiver/transmitter input and output clock frequency.
J	Deserialization factor (width of parallel data bus).
W	PLL multiplication factor.
t_{RISE}	Low-to-high transmission time.
t_{FALL}	High-to-low transmission time.
Timing unit interval (TUI)	The timing budget allowed for skew, propagation delays, and data sampling window. (TUI = 1/(Receiver Input Clock Frequency × Multiplication Factor) = t_C/w).
f_{HSDR}	Maximum/minimum LVDS data transfer rate (f_{HSDR} = 1/TUI), non-DPA.
$f_{HSDRDPA}$	Maximum/minimum LVDS data transfer rate ($f_{HSDRDPA}$ = 1/TUI), DPA.
Channel-to-channel skew (TCCS)	The timing difference between the fastest and slowest output edges, including t_{CO} variation and clock skew. The clock is included in the TCCS measurement.
Sampling window (SW)	The period of time during which the data must be valid in order to capture it correctly. The setup and hold times determine the ideal strobe position within the sampling window.
Input jitter	Peak-to-peak input jitter on high-speed PLLs.
Output jitter	Peak-to-peak output jitter on high-speed PLLs.
t_{DUTY}	Duty cycle on high-speed transmitter output clock.
t_{LOCK}	Lock time for high-speed transmitter and receiver PLLs.

Table 5–89 shows the high-speed I/O timing specifications for -3 speed grade Stratix II devices.

Table 5–89. High-Speed I/O Specifications for -3 Speed Grade (Part 1 of 2) *Notes (1), (2)*

Symbol	Conditions	-3 Speed Grade			Unit
		Min	Typ	Max	
f_{HSCLK} (clock frequency) $f_{HSCLK} = f_{HSDR} / W$	W = 2 to 32 (LVDS, HyperTransport technology) *(3)*	16		520	MHz
	W = 1 (SERDES bypass, LVDS only)	16		500	MHz
	W = 1 (SERDES used, LVDS only)	150		717	MHz

PLL Timing Specifications

Tables 5–92 and 5–93 describe the Stratix II PLL specifications when operating in both the commercial junction temperature range (0 to 85 °C) and the industrial junction temperature range (–40 to 100 °C).

Table 5–92. Enhanced PLL Specifications (Part 1 of 2)

Name	Description	Min	Typ	Max	Unit
f_{IN}	Input clock frequency	2		500	MHz
f_{INPFD}	Input frequency to the PFD	2		420	MHz
f_{INDUTY}	Input clock duty cycle	40		60	%
$f_{EINDUTY}$	External feedback input clock duty cycle	40		60	%
$t_{INJITTER}$	Input or external feedback clock input jitter tolerance in terms of period jitter. Bandwidth ≤ 0.85 MHz		0.5		ns (p-p)
	Input or external feedback clock input jitter tolerance in terms of period jitter. Bandwidth > 0.85 MHz		1.0		ns (p-p)
$t_{OUTJITTER}$	Dedicated clock output period jitter			250 ps for ≥ 100 MHz `outclk` 25 mUI for < 100 MHz `outclk`	ps or mUI (p-p)
t_{FCOMP}	External feedback compensation time			10	ns
f_{OUT}	Output frequency for internal global or regional clock	1.5 *(2)*		550.0	MHz
$t_{OUTDUTY}$	Duty cycle for external clock output (when set to 50%).	45	50	55	%
$f_{SCANCLK}$	Scanclk frequency			100	MHz
$t_{CONFIGPLL}$	Time required to reconfigure scan chains for enhanced PLLs		$174/f_{SCANCLK}$		ns
f_{OUT_EXT}	PLL external clock output frequency	1.5 *(2)*		550.0 *(1)*	MHz